

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re the Application of: **Kar-Roy et al.**

Serial No.:

Filed:

For: **Method For Fabricating a High Density  
Composite MIM Capacitor with Reduced  
Voltage Dependence in Semiconductor Dies**

Examiner:

Group Art Unit:

This is a Rule 1.53(b) divisional of parent  
U.S. Application entitled "A High Density Composite  
MIM Capacitor with Reduced Voltage Dependence in  
Semiconductor Dies," Serial No. 10/410,937  
Filed April 9, 2003 and assigned to the  
assignee of the present application.

**PRELIMINARY AMENDMENT TO DIVISIONAL APPLICATION**

Honorable Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir/Madam:

This amendment is directed to the accompanying 37 CFR §1.53(b) divisional application.  
This divisional application is classified in Class 438, Subclass 396. The pending parent  
application Serial No. 10/410,937 is classified in Class 257, Subclass 532 in Art Unit 2822.  
Please enter the following amendments in the present Rule 1.53(b) divisional application.